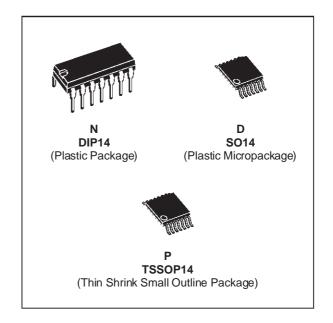


TL084 TL084A - TL084B

GENERAL PURPOSEJ-FET QUAD OPERATIONAL AMPLIFIERS

- WIDE COMMON-MODE (UP TO Vcc⁺) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE: 16V/µs (typ)



DESCRIPTION

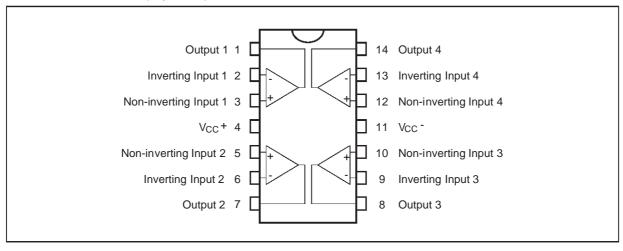
The TL084, TL084A and TL084B are high speed J–FET input quad operational amplifiers incorporating well matched, high voltage J–FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and low offset voltage temperature coefficient.

ORDER CODES

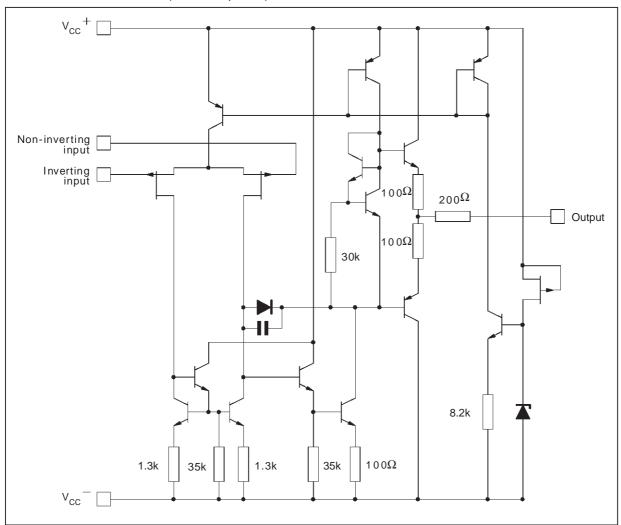
Part Number	Temperature	Package				
I alt Nullibel	Range	N	D	Р		
TL084M/AM/BM	−55°C, +125°C	•	•	•		
TL084I/AI/BI	−40°C, +105°C	•	•	•		
TL084C/AC/BC	0°C, +70°C	•	•	•		
Examples: TL084CN, TL084CD						

PIN CONNECTIONS (top view)



January 1999 1/11

SCHEMATIC DIAGRAM (each amplifier)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vcc	Supply Voltage - (note 1)	±18	V
Vi	Input Voltage - (note 3)	±15	V
V _{id}	Differential Input Voltage - (note 2)	±30	V
P _{tot}	Power Dissipation	680	mW
	Output Short-circuit Duration - (note 4)	Infinite	
T _{oper}	Operating Free Air Temperature Range TL084C,AC,BC TL084I,AI,BI TL084M,AM,BM	0 to 70 -40 to 105 -55 to 125	°C
T _{stg}	Storage Temperature Range	-65 to 150	°C

 All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}⁻.
 Differential voltages are at the non-inverting input terminal with respect to the inverting input terminal.
 The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
 The output may be shorted to ground or to either supply. Temperature and /or supply voltages must be limited to ensure that the dissipation rating is not exceeded. Notes:

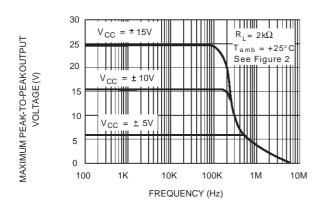
ELECTRICAL CHARACTERISTICS

 $V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

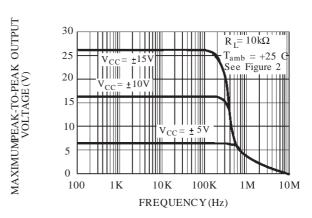
Symbol	Parameter		TL084I,M,AC,AI, AM,BC,BI,BM			TL084C		
		Min.	Тур.	Max.	Min.	Тур.	Max.	
V _{io}	$\begin{array}{c} \text{Input Offset Voltage } (R_S=50\Omega) \\ T_{amb}=25^{\circ}C & TL084 \\ TL084A & TL084B \\ T_{min.} \leq T_{amb} \leq T_{max.} & TL084 \\ TL084A & TL084A \\ TL084B & TL084B \\ \end{array}$		3 3 1	10 6 3 13 7 5		3	10 13	mV
DV _{io}	Input Offset Voltage Drift		10			10		μV/°C
l _{io}	Input Offset Current * $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$		5	100 4		5	100 4	pA nA
l _{ib}	Input Bias Current * $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$		20	200 20		30	400 20	pA nA
A _{vd}	$ \begin{array}{l} \text{Large Signal Voltage Gain } (R_L = 2k\Omega, \ V_O = \pm 10V) \\ T_{amb} = 25^{\circ}C \\ T_{min.} \leq T_{amb} \leq T_{max.} \end{array} $	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio (R _S = 50Ω) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	80 80	86		70 70	86		dB
Icc	Supply Current, per Amp, no Load $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
V_{icm}	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio (R _S = 50Ω) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	80 80	86		70 70	86		dB
los	Output Short-circuit Current $T_{amb} = 25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	10 10	40	60 60	10 10	40	60 60	mA
±V _{OPP}	$ \begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = 25^{\circ}C & R_{L} = 2k\Omega \\ R_{L} = 10k\Omega \\ T_{min.} \leq T_{amb} \leq T_{max.} & R_{L} = 2k\Omega \\ R_{L} = 10k\Omega \end{array} $	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate (V_{in} = 10V, R_L = 2k Ω , C_L = 100pF, T_{amb} = 25°C, unity gain)	8	16		8	16		V/μs
t _r	Rise Time ($V_{in} = 20 \text{mV}$, $R_L = 2 \text{k}\Omega$, $C_L = 100 \text{pF}$, $T_{amb} = 25 ^{\circ}\text{C}$, unity gain)		0.1			0.1		μs
K _{OV}	Overshoot ($V_{in} = 20$ mV, $R_L = 2$ k Ω , $C_L = 100$ pF, $T_{amb} = 25$ °C, unity gain)		10			10		%
GBP	Gain Bandwidth Product (f = 100kHz, $T_{amb} = 25^{\circ}C$, $V_{in} = 10mV$, $R_L = 2k\Omega$, $C_L = 100pF$)	2.5	4		2.5	4		MHz
Ri	Input Resistance		10 ¹²			10 ¹²		Ω
THD	Total Harmonic Distortion (f = 1kHz, A_V = 20dB, R_L = 2k Ω , C_L = 100pF, T_{amb} = 25°C, V_O = 2V _{PP})		0.01			0.01		%
en	Equivalent Input Noise Voltage (f = 1kHz, $R_s = 100\Omega$)		15			15		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
Øm	Phase Margin		45			45		Degrees
V _{O1} /V _{O2}	Channel Separation (A _v = 100)		120			120		dB

^{*} The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.

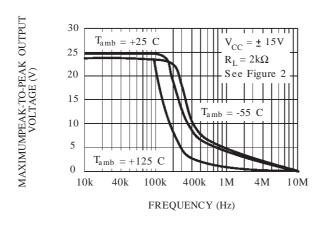
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY



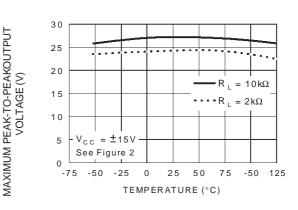
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY



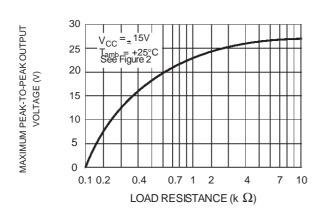
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREQUENCY



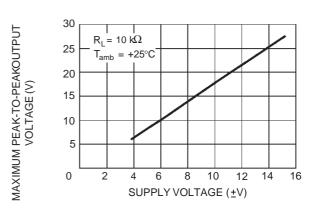
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS FREE AIR TEMP.



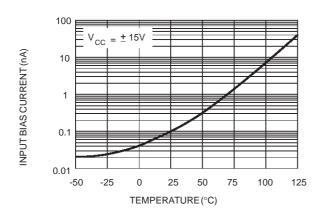
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS LOAD RESISTANCE



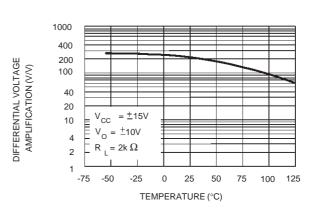
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE VERSUS SUPPLY VOLTAGE



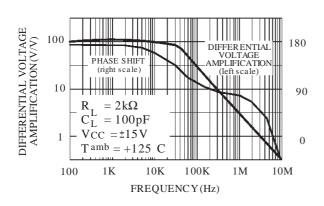
INPUT BIAS CURRENT VERSUS FREE AIR TEMPERATURE



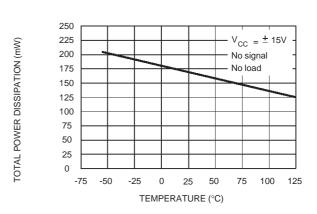
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION VERSUS FREE AIR TEMPERATURE



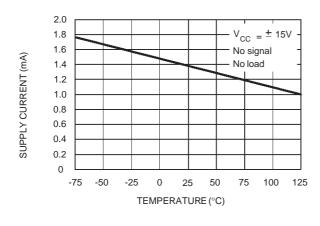
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT VERSUS FREQUENCY



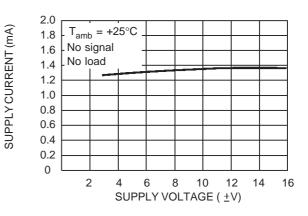
TOTAL POWER DISSIPATION VERSUS FREE AIR TEMPERATURE



SUPPLY CURRENT PER AMPLIFIER VERSUS FREE AIR TEMPERATURE

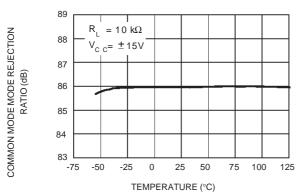


SUPPLY CURRENT PER AMPLIFIER VERSUS SUPPLY VOLTAGE

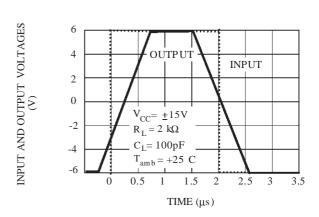


COMMON MODE REJECTION RATIO

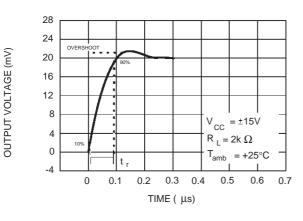
VERSUS FREE AIR TEMPERATURE



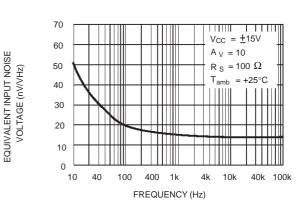
VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



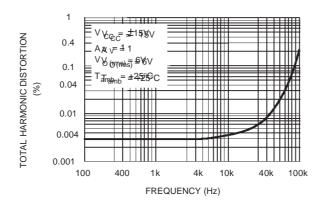
OUTPUT VOLTAGE VERSUS ELAPSED TIME



EQUIVALENT INPUT NOISE VOLTAGE VERSUS FREQUENCY



TOTAL HARMONIC DISTORTION VERSUS FREQUENCY



PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

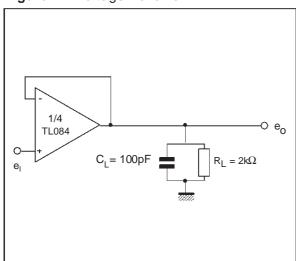
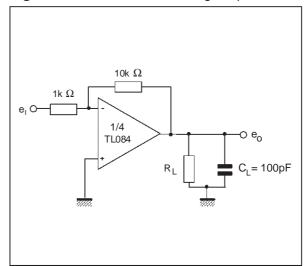
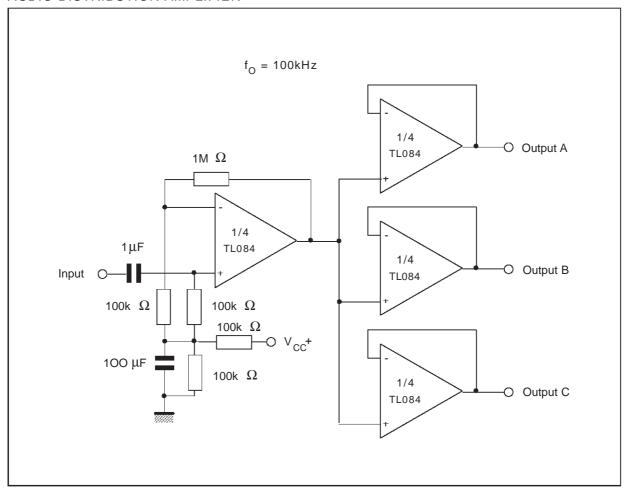


Figure 2 : Gain-of-10 Inverting Amplifier



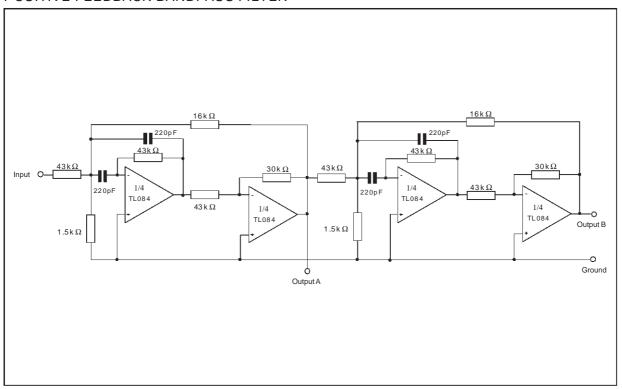
TYPICAL APPLICATIONS

AUDIO DISTRIBUTION AMPLIFIER

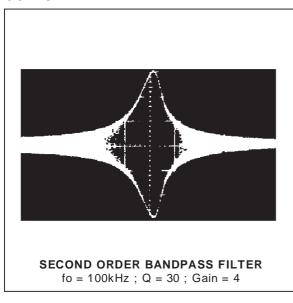


TYPICAL APPLICATIONS (continued)

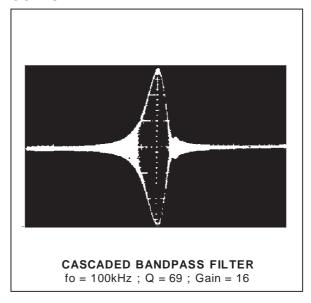
POSITIVE FEEDBACK BANDPASS FILTER



OUTPUT A

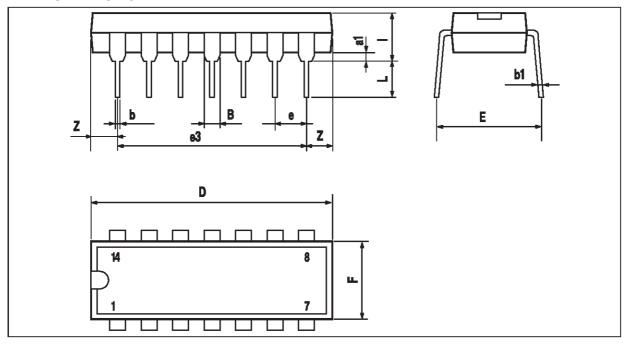


OUTPUT B



PACKAGE MECHANICAL DATA

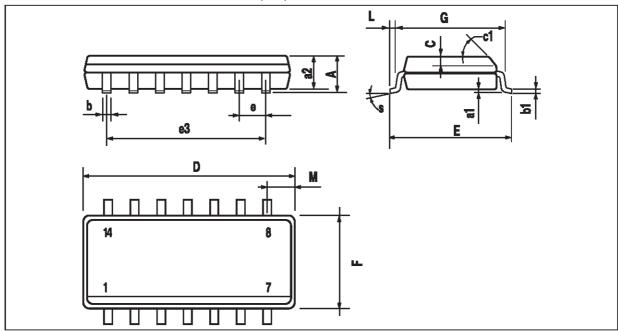
14 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
a1	0.51			0.020			
В	1.39		1.65	0.055		0.065	
b		0.5			0.020		
b1		0.25			0.010		
D			20			0.787	
E		8.5			0.335		
е		2.54			0.100		
e3		15.24			0.600		
F			7.1			0.280	
i			5.1			0.201	
L		3.3			0.130		
Z	1.27		2.54	0.050		0.100	

PACKAGE MECHANICAL DATA

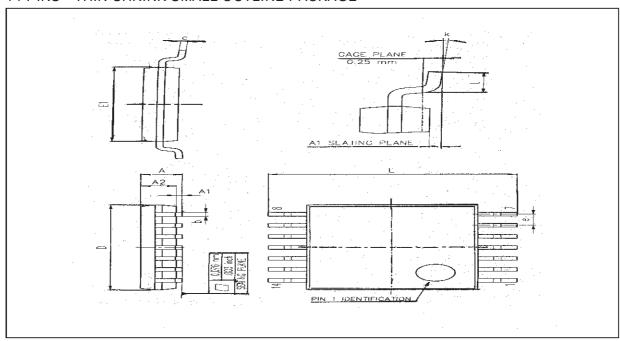
14 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches			
Difficusions	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.75			0.069	
a1	0.1		0.2	0.004		0.008	
a2			1.6			0.063	
b	0.35		0.46	0.014		0.018	
b1	0.19		0.25	0.007		0.010	
С		0.5			0.020		
c1			45°	(typ.)			
D	8.55		8.75	0.336		0.334	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		7.62			0.300		
F	3.8		4.0	0.150		0.157	
G	4.6		5.3	0.181		0.208	
L	0.5		1.27	0.020		0.050	
M			0.68			0.027	
S	8° (max.)						

PACKAGE MECHANICAL DATA

14 PINS - THIN SHRINK SMALL OUTLINE PACKAGE



Dim.	Millimeters			Inches			
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.20			0.05	
A1	0.05		0.15	0.01		0.006	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.15	
С	0.09		0.20	0.003		0.012	
D	4.90	5.00	5.10	0.192	0.196	0.20	
E		6.40			0.252		
E1	4.30	4.40	4.50	0.169	0.173	0.177	
е		0.65			0.025		
k	0°		8°	0°		8°	
I	0.50	0.60	0.75	0.09	0.0236	0.030	

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